

P-Channel Enhancement Mode MOSFET

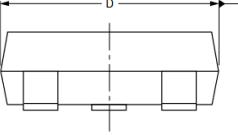
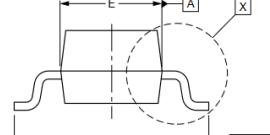
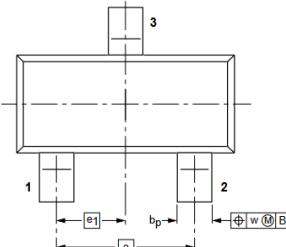
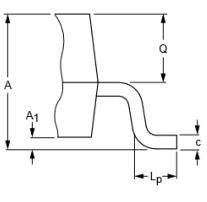
Primary characteristics			
Symbol	Parameter	Value	Unit
I_D	Continuous drain current (@ $T_c=25^\circ\text{C}$)	-7.0	A
V_{DS}	Drain source voltage	-20	V

Features

- SOT-23 case for easy automatic insertion
- Pb-free and RoHS compliant

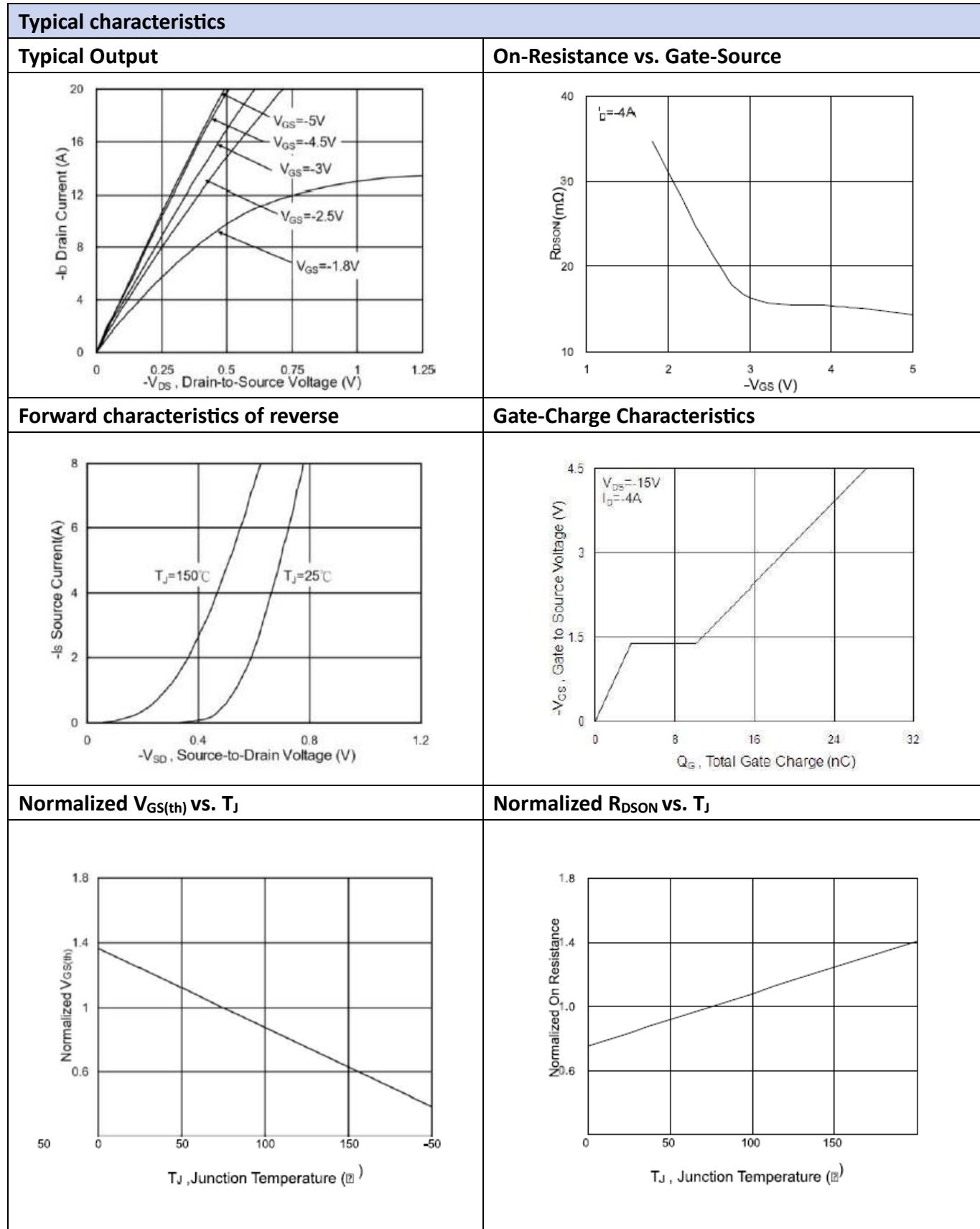
Application

- Quick charge
- Electronic cigarette
- Uninterruptable power supply

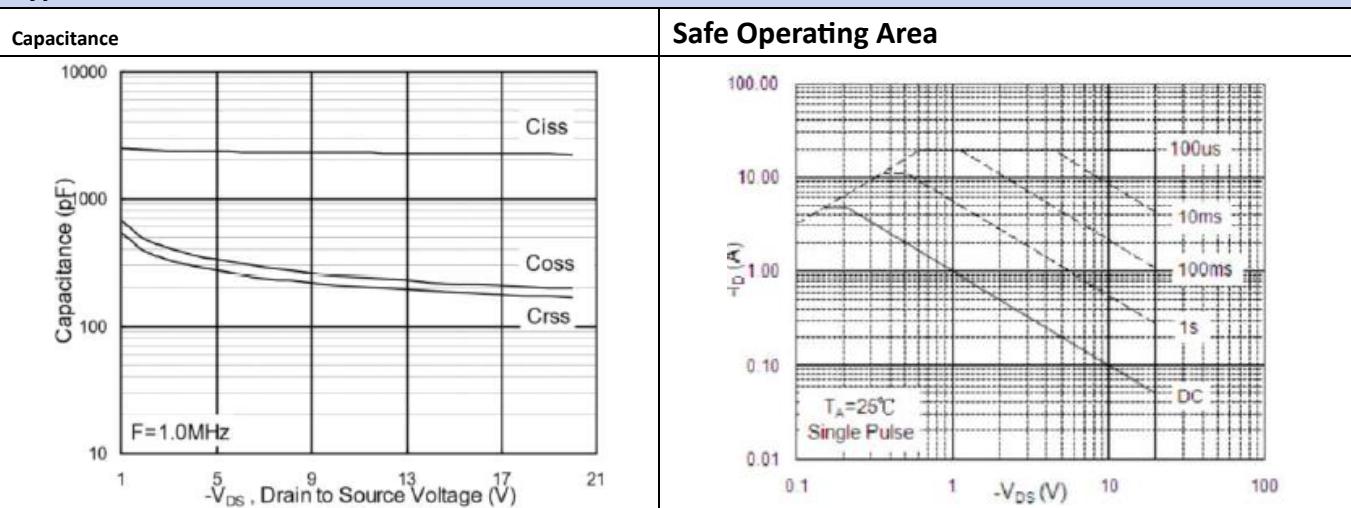
Case dimensions													
													
													
1 – Gate; 2 – Source; 3 – Drain													
SOT-23 (TO-236AB)													
Unit	A	$A_{1\max}$	b_p	c	D	E	e	e_1	H_E	l_p	Q	v	w
mm	1.0 ±0.1	0.1	0.43 ±0.05	0.12 ±0.03	2.9 ±0.1	1.3 ±0.1	1.9	0.95	2.3 ±0.2	0.3 ±0.15	0.5 ±0.05	0.2	0.1

Absolute maximum ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)				
Characteristic	Symbol	Value		Unit
Drain-source voltage	V_{DS}	-20		V
Gate-source voltage	V_{GS}	±12		V
Continuous drain current	I_D	-7.0		A
Pulsed drain current ¹⁾	I_{DM}	-23.8		A
Power Dissipation	P_D	2.0		W
Thermal resistance junction-ambient ¹⁾	$R_{\theta JA}$	62.5		°C/W
Operating junction temperature range	T_J, T_{STG}	-55 ~ 150		°C

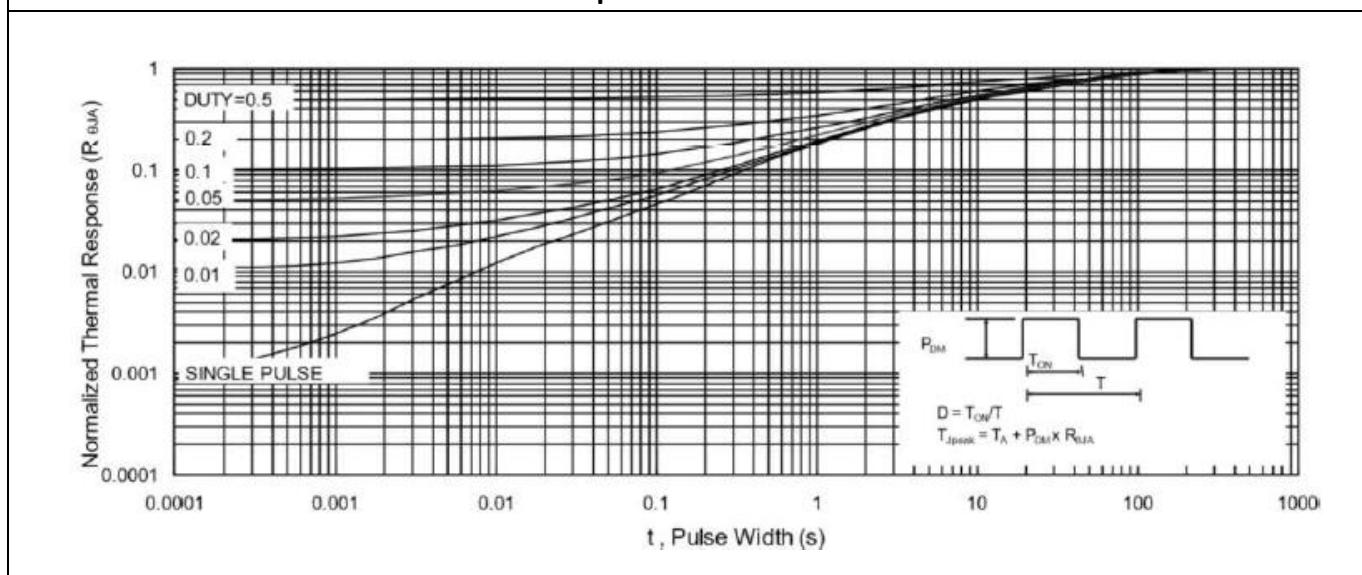
Electrical characteristics ($T_A = 25^\circ\text{C}$)						
Characteristic	Test condition	Symbol	Value			Unit
			Min.	Typ.	Max.	
Drain-source breakdown voltage	$V_{GS}=0\text{V}$, $I_D=250\mu\text{A}$	$V_{(BR)DSS}$	-20	-22	-	V
Zero gate voltage drain current	$V_{DS}=-20\text{V}$, $V_{GS}=0\text{V}$	I_{DSS}	-	-	1.0	μA
Gate to body leakage current	$V_{GS}=\pm 12\text{V}$, $V_{DS}=0\text{V}$	I_{GSS}	-	-	± 100	nA
Gate threshold voltage	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	$V_{GS(\text{TH})}$	-0.5	-0.7	-1.2	V
Drain-source on-state resistance ³⁾	$V_{GS}=4.5\text{V}$, $I_D=6.0\text{A}$	$R_{DS(\text{ON})}$	-	20	25	$\text{m}\Omega$
	$V_{GS}=2.5\text{V}$, $I_D=5.0\text{A}$		-	28	35	
Dynamic electrical characteristics						
Characteristic	Test condition	Symbol	Value			Unit
			Min.	Typ.	Max.	
Input capacitance	$V_{DS}=10\text{V}$ $V_{GS}=0\text{V}$ $f=1.0\text{MHz}$	C_{iss}	-	2000	-	pF
Output capacitance		C_{oss}	-	242	-	
Reverse transfer capacitance		C_{rss}	-	231	-	
Total gate charge	$V_{DS}=10\text{V}$ $V_{GS}=4.5\text{V}$ $I_D=3.0\text{A}$	Q_g	-	15.3	-	nC
Gate source charge		Q_{gs}	-	2.2	-	
Gate drain ("Miller") charge		Q_{gd}	-	4.4	-	
Switching characteristics						
Characteristic	Test condition	Symbol	Value			Unit
			Min.	Typ.	Max.	
Turn on delay time	$V_{DS}=10\text{V}$ $V_{GS}=4.5\text{V}$ $I_D=7.0\text{A}$ $R_G=2.5\Omega$	$t_{d(on)}$	-	10	-	ns
Turn on rise time		t_r	-	31	-	
Turn off delay time		$t_{d(off)}$	-	28	-	
Turn off fall time		t_f	-	7.8	-	
Source drain diode characteristics						
Characteristic	Test condition	Symbol	Value			Unit
			Min.	Typ.	Max.	
Drain-source diode forward voltage ³⁾	$I_S=7.0\text{A}$, $V_{GS}=0\text{V}$	V_{SD}	-	-0.8	1.2	V



Typical characteristics



Normalized maximum transient thermal impedance



Ordering information

Part Number	Package	Shipping Quantity	Dimensions
AKS2307A	SOT-23	3000 pcs / reel	---

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